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ESE - 2020 PRELIMINARY EXAMINATION

Questions with Detailed Solutions

ELECTRONICS & TELECOMMUNICATION ENGINEERING (SET-C)

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ESE - 2020 Preliminary Examination Electronics & Telecommunication Engineering

SET - C 05/01/20

- Which one of the following is commonly used piezoelectric ceramics? 01.
 - (a) Yttrium oxide (Y_2O_3)
 - (c) Barium titanate (BaTiO₃)
- 01. Ans: (c)
- Sol: Piezoelectric materials
 - (1) Barium Titanate (BaTiO₃)
 - (2) Rochelle's salt
 - (3) Quartz
 - (4) PVDF
- 02. The detailed information regarding the mechanism of fracture is available from microscopic examination, normally using scanning electron microscopy, and its study is termed as
 - (b) Fractographic (a) Microscopic (d) Nanoscopic
 - (c) Atroscopic
- 02. Ans: (b)
- Sol: Fractography is the study of the fracture surface of material.
- A transformer core is wound with a coil carrying an alternating current at a frequency of 50Hz. 03. The magnetization is uniform throughout the core volume of 0.01 m^3 , the hysteresis loop has an area of 60,000 units when the axes are drawn in units of 10^{-4} Wb m⁻² and 10^{2} A m⁻¹ The power loss due to hysteresis will be (b) 250W
 - (a) 200W

(c) 300W

(d) 350W

- **03.** Ans: (c)
- **Sol:** Hysteresis loss = $Loss/unit \times no.$ of units

Loss/unit = (volume) (f)(B)(H) $= (0.01) (50)(10^{-4})(10^{-2})$ $= 50 \times 10^{-4}$ watts/unit Hysteresis loss = $50 \times 10^{-4} \times 60000$

= 300 watts

- (b) Boron carbide (B_4C)
- (d) Tungsten carbide (WC)



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	ACE Engineering Publications		3		E & T Engineering
04.	In a 440 V, 50Hz tra	nsformer, the total ir	on loss is	s 2300 W. W	/hen the applied voltage is 220 V at
	25 Hz, the total iron	loss is 750 W. The e	ddy curr	ent loss at th	e normal voltage and frequency will
	be				
	(a) 1600W	(b) 1400W	(c)	1200W	(d) 1000W
04.	Ans: (a)				
Sol:	440V, 50Hz, $w_i = 23$	00w			
	220V, 25Hz, $w_i = 75$	i0w			
	$B_{max} = \frac{v}{f} = \frac{440}{50} = \frac{22}{2}$	$\frac{20}{5} = \text{const.}$			
	\therefore w _i = Af + Bf ²		EERIA		
	2300 = A(50) + B(50)	$))^2$	ELILI	ACA	
	7500 = A(25) + B(25)	5)2 44			
	46 = A + 50B	T N			
	30 = A + 25B				
	16 = 25 B				
	B = 0.64				
	46 = A + 50(0.64)				
	46 = A + 32	C;		005	
	A = 14		nce i	773	
	\therefore w _i at f (50 Hz) =	$Af + Bf^2$			
	= 14(50) -	$+0.64)(50)^2$			
	= 700 + 10	600			
	= 2300w				
	$w_n = 700w$				
	$w_e = 1600 w.$				

Engineering Publications	4	ESE_20 Questions with Solutions
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- 05. Type-I classified superconducting materials on the basis of magnetic response are completely in diamagnetic state where magnetic field is excluded from the body of material due to the phenomenon, known as
 - (a) Anisotropic effect (b) Meissner effect
 - (c) Magnetic effect (d) Electrical effect

05. Ans: (b)

Sol: Meissner effect: It is expulsion of magnetic flux lines by the super conductor



- 06. Which of the following statements are correct for superconductors?
 - 1. A substance losses its electrical resistance below certain temperature.
 - 2. Superconducting elements have greater electrical resistivity at room temperature
 - 3. On adding impurities to superconducting elements its transition temperature is increased
 - (a) 1, 2 and 3 (b) 1 and 2 only
 - (c) 1 and 3 only (d) 2 and 3 only

06. Ans: (a)

- Sol: A substance losses its electrical resistance below certain temperature.
 Superconducting elements have greater electrical resistivity at room temperature.
 On adding impurities to superconducting elements its transition temperature is increased.
 So, All statements are correct .
- 07. Which one of the following is composed of two characteristics: conformity and the unmber of significant figures to which a measurement may be made?

(a) Sensitivity (b) Resolution (c) Accuracy (d) Precision

- 07. Ans: (a)
- **Sol:** Sensitivity is the only terms which related to both conformity & the number of significant figures. The most appropriate option is sensitivity.

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- 08. A 1-mA meter movement with an internal resistance of 100Ω is to be converted into a 0-100 mA ammeter. The value of shunt resistance will be
 - (a) 2.41Ω (b) 2.01Ω (c) 1.41Ω (d) 1.01Ω

08. Ans: (d)

Sol: $I_m = 1mA$, $R_m = 100\Omega$, I = 100mA

$$R_{sh} = ?$$

$$R_{sh} = \frac{R_{m}}{((I/I_{m})-1)} = \frac{100}{\left(\frac{100 \times 10^{-3}}{1 \times 10^{-3}} - 1\right)}$$
$$= \frac{100}{100-1} = \frac{100}{99}$$
$$= 1.01\Omega$$

Which of the following methods are used for producing damping torque in analog instruments? 09.

Since 1995

- 1. Air friction damping
- 2. Fluid friction damping
- 3. Eddy current damping
- 4. Electromagnetic damping
- (a) 1, 2 and 3 only
- (b) 1, 2 and 4 only
- (c) 1, 3 and 4 only
- (d) 1, 2, 3 and 4

09. Ans: (d)

- Sol: In analog Instrument the following dampings are used.
 - 1. Air friction damping
 - 2. Fluid friction damping
 - 3. Eddy current damping
 - 4. Electromagnetic damping

	ACE Engineering Publications	7		E & T Engineering			
10.	Which of the following methods are used for	or mea	surement of low resista	ance?			
	1. Ammeter voltmeter method						
	2. kelvin's double bridge method						
	3. maxwell's bridge method						
	4. Potentiometer method						
	(a) 1, 2 and 3 only (b) 1, 2 and 4 only		(c) 1, 3 and 4 only	(d) 2, 3 and 4 only			
10.	Ans: (b)						
Sol:	For low Resistance measurement						
	Kelvin double bridge method and potention	neter i	is used.				
11.	A thermometer reads 95.45°C and the static	corre	ction given in the corre	ection curve is –0.08°C.			
	The true value of temperature will be		ACA				
	(a) 95.37°C (b) 95.45°C	(c)	95.65°C (d)	95.73°C			
11.	Ans: (a)		3				
Sol:	$A_{\rm m} = 95.45^{\rm o}{\rm C}$						
	$\delta C = -0.08^{\circ}C$						
	$A_t = ?$						
	$\delta C = A_t - A_m$						
	$-0.08 = A_t - 95.45$						
	$A_t = 95.37^{\circ}C.$		005				
12.	Unit step response of first order system with	ce 1 trans	fer function $G(s) = \frac{1}{1}$	— is			
		. t/τ		τs			
10	(a) $1 - e^{-\alpha x}$ (b) $1 + e^{-\alpha x}$ (c) 1	$+ e^{-\epsilon}$	(d) $1 - e^{a t}$				
12.	Ans: (a) $C(x) = 1$						
Sol:	$\frac{C(s)}{R(s)} == G(s) = \frac{1}{1 + \tau s}$						
	$\mathbf{R}(\mathbf{s}) = 1/\mathbf{s}$						
	$C(s) = \frac{1}{s(1+\tau s)} = \frac{1}{s} - \frac{\tau}{1+\tau s}$						
	$C(s) = \frac{1}{s} - \frac{\tau}{\tau(s+1/\tau)} $ App	ly — ^I	$\xrightarrow{LT} C(t) = (l - e^{-t/\tau})u(t)$)			

ACE Engineering Publications	8	ESE_20 Questions with Solutions						
What are the advantages of resistance potentiometer								
1. They are inexpensive								
2. They are useful for measurement of large amplitudes of displacement								
3. Their electrical efficiency is very high an	d they	provide sufficient output to permit control						
operations without further amplification								
(a) 1 and 2 only (b) 1 and 3 only	(c)	2 and 3 only (d) 1, 2 and 3						
Ans: (d)								
Resistance potentiometers are cheap & simp	ple to	operate						
Resistive potentiometers are useful for measure	surem	ent of large amplitudes of displacement.						
Resistive potentiometers have very high ele	ctrical	efficiency & provide sufficient output to permit						
control operations without further amplifica	tions.	NG AC						
What are the salient features of thermistors?	? 八	AO ^W						
1. They are compact, rugged and inexpensiv	ve	3						
2. They have good stability when properly a	aged							
3. The response time of thermistors can vary	y from	a fraction of a second to minutes, depending on						
the size of the detecting mass and thermal capacity of the thermistor								
(a) 1 and 2 only (b) 1 and 3 only	(c)) 2 and 3 only (d) 1, 2 and 3						
Ans: (d)								
The thermistors are compact, rugged and in	The thermistors are compact, rugged and inexpensive.							
		0.05						

Thermistors have good stability when properly aged.

The response time of thermistors depending on the size of the detecting mass & thermal capacity of the thermistor.

- 15. Which of the following land line telemetry systems are available ?
 - 1. Voltage telemetry systems
 - 2. Current telemetry systems
 - 3. Position telemetry systems
 - 4. Resistive telemetry systems

(a) 1, 2 and 3 only (b) 1, 2 and 4 only (c) 1, 3 and 4 only (d) 2, 3 and 4 only

15. Ans: (a)

13.

13.

Sol:

14.

14.

Sol:

Sol: The landline telemetry systems available are voltage, current and position.



	ACE Engineering Publications	10		ESE_20 Questions with Solutions
16.	A platinum thermometer has a resistance	of 100Ω	2 at 25°C. Tl	he resistance at 65°C for its resistance
	temperature co-efficient of 0.00392/°C w	ll be ne	arly	
	(a) 107.3Ω (b) 115.7Ω	(c)	123.3Ω	(d) 131.7Ω
16.	Ans: (b)			
Sol:	$R_1 = 100 \ \Omega$ at $T_1 = 25^{\circ}C$			
	R_2 at $T_2 = 65^{\circ}C$			
	$\alpha = 0.00392(1/^{\circ}C)$			
	$R_2 = R_1(1 + \alpha(T_2 - T_1))$			
	= 100 (1 + 0.00392(65 - 25))	EDIA		
	= 115.68 Ω	ENU	VGACA	
	≅ 115.7		*	en la
	T I I			2
17.	The capacitive transducer works on the pr	inciple	of change of	f capacitance which may be caused
	by change in			
	1. Dielectric constant			
	2. Overlapping area of plates			
	3. Distance between the plates			
	(a) 1 and 2 only (b) 1 and 3	3 only	
	(c) 2 and 3 only (d) 1, 2 an	d 3	
17.	Ans: (d)		סוי	
Sol:	(i) Capacitance change due to changes in	dielectri	ic constant	
	C α ε			

(ii) Capacitance change due to changes in overlapping area of plates

 $C\,\alpha\,A$

(iii) Capacitance change due to changes in distance between the plates

 $C\alpha \frac{1}{d}$

	ACE	11		E & T Engineering		
18.	What are the advantages of capacitive trans	ducers	?			
	1. They are extremely sensitive					
	2. They have a high input impedance and therefore the lading effects are minimum					
	3. They have a good frequency response					
	(a) 1 and 2 only (b) 1 and 3 only	(c)	2 and 3 only	(d) 1, 2 and 3		
18.	Ans: (d)					
Sol:	Advantages of capacitive transducers are					
	(i) High sensitivity					
	(ii) Good frequency response					
	(iii) High input impedance so minimum load	ding e	ffect.			
	GINE	:KIA	IG AC			
19.	What are the properties of a tree in a networ	k grap	oh?			
	1. It consists of all the nodes of the graph		12			
	2. If the graph as N number of nodes, the tre	ee will	have (N-1) branche	s		
	3. There will be only one closed path in the	tree				
	(a) 1, 2 and 3 (b) 1 and 3 only	(c)	1 and 2 only	(d) 2 and 3 only		
19.	Ans: (c)					
Sol:	Properties of Tree:					
	1. It contains all nodes in the graph					
	2. The number of twigs (branches of tree)	ce 1	995	,		
	=(N-1)					
	N = Number of nodes					
	3. No closed path shall occur					
20		<u> </u>	1			
20.	which one of the following is the property of	of inci	dence matrix?			
	(a) Determinant of the incidence matrix of a		a loop is zero	or of the human above		
	(c) Algebraic sum of the row entries of an is	nider	ce matrix is zero			
	(d) Algebraic sum of the column entries of a	in inci	dence matrix is alwa	VS one		
	(u) Aigeorate sum of the column chilles of a		uchec maula is alwa	ys one		

	ACE Engineering Publications	12	ESE_	20 Questions with Solutions
20.	Ans: (a)			
Sol:	Properties of Incidence Matrix (A)			
	1. The sum of the entries in any column is z	ero		
	2. The determinant of the incidence matrix of	of a clo	osed loop is zero	
	3. The rank of the incidence matrix of a con	nected	l graph is $(n-1)$	
21.	The Laplace transform of a function f(t) is	F(s) =	$\frac{s+2}{(s+2)^2+10^2}$. The	value of f(0) will be
	(a) -1 (b) 0 (c) 1	l	(d) 2	
21.	Ans: (c)	- 11		
Sol:	$F(s) = \frac{s+2}{(s+2)^2 + 10^2}$		ACAD	
	$F(s) = \frac{s+2}{s^2 + 4s + 104}$		EX	
	$f(0) = \underset{s \to \infty}{\text{Lt}} sF(s) = \underset{s \to \infty}{\text{Lt}} \frac{s(s+2)}{s^2 + 4s + 104}$			
	$= \lim_{s \to \infty} \frac{s^2 + 2s}{s^2 + 4s + 104} = \lim_{s \to \infty} \frac{s^2 (1 + 2/s)}{s^2 (1 + 4/s + 104)}$	$\left(\frac{1}{1/s^2}\right)$	= 1	
22.	A function, in Laplace domain is given by	F(s)=	$\frac{2}{s} \frac{1}{s+3}$	
	Its value by final value theorem in t domain	will t	be	
	(a) $\lim_{t\to\infty} f(t) = 3$ (b) $\lim_{t\to\infty} f(t) = 2$	(c)	$\lim_{t\to\infty} f(t) = 1$	(d) $\lim_{t\to\infty} f(t) = 4$

22. Ans: (b)

Sol:
$$F(s) = \frac{2}{s} - \frac{1}{s+3}$$

Apply ILFT $f(t) = (2 - e^{-3t})$
Lt $f(t) = \underset{t \to \infty}{\text{Lt}} (2 - e^{-3t}) = 2$

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23. Consider the following experimental readings for a two-port network:

	V_1	V_2	I ₁	I ₂
Output Open	100V	60V	10 A	0
Input Open	30V	40V	0	3A

The values of Z₁₁, Z₁₂, Z₂₁, and Z₂₂, respectively are

(a) 10 Ω , 10 Ω , 6 Ω and 13.33 Ω (b) 6 Ω , 10 Ω , 10 Ω and 6 Ω

(c) 10Ω , 6Ω , 10Ω and 13.33Ω (d) 6Ω , 10Ω , 6Ω and 10Ω

23. Ans: (a)

Sol: For Z-Parameters

 $V_1 = Z_{11}I_1 + Z_{12}I_2$

 $V_2 = Z_{21}I_1 + Z_{22}I_2$

When $I_2 = 0$, $Z_{11} = \frac{V_1}{I_1} = \frac{100}{10} = 10\Omega$

$$Z_{21} = \frac{V_2}{I_1} = \frac{60}{10} = 6\Omega$$

When $I_1 = 0$, $Z_{22} = \frac{V_2}{I_2} = \frac{40}{3} = 13.33\Omega$

- $Z_{12} = \frac{V_1}{I_2} = \frac{30}{3} = 10\Omega$ Since 1995 $Z_{11} = 10\Omega, Z_{12} = 10\Omega, Z_{21} = 6\Omega, Z_{22} = 13.33\Omega$
- 24. The Laplace transform of $f(t) = 1 e^{-2t}$ is

(a)
$$\frac{2}{s(s+2)}$$
 (b) $\frac{1}{s(s+2)}$ (c) $\frac{2}{s(s-2)}$ (d) $\frac{1}{s(s-2)}$

24. Ans: (a)

Sol: L.T of $f(t) = 1 - e^{-2t}$ is

$$F(s) = \frac{1}{s} - \frac{1}{s+2} = \frac{2}{s(s+2)}$$







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25. For a two-port network, condition of Symmetry	metry in	terms of z-p	arameters is
(a) $z_{12} = z_{21}$ (b) $z_{11} = z_{22}$	(c)	$z_{11} = z_{21}$	(d) $z_{12} = z_{22}$
25. Ans: (b)			
Sol: Condition for symmetry $z_{11} = z_{22}$			
26 For a two-port network the condition of R	eciproc	ity in terms o	f h-narameter is
(a) $h_{12} = h_{21}$ (b) $h_{12} = h_{22}$	(c)	$h_{12} = -h_{21}$	(d) $h_{12} = -h_{22}$
26. Ans: (c)		12 21	() 12 22
Sol: Condition for reciprocity			
$h_{12} = -h_{21}$			
27. The initial current is $i(0^+)$, clockwise and t	he circu	iit current bei	ng i(t) and v(f) = $L \frac{di(t)}{dt}$
The above representation in Laplace transf	form is	~~O	
(a) $V(s) = [sLI(s)-Li(0^+)]$	(b)	V(s) = [sLI(s)])]
(c) $V(s) = [Li(0^+)]$	(d)	V(s) = [sLI(($(0^{+}) + Li(s)$]
27. Ans: (a)			
Sol: $V(t) = L \frac{di(t)}{dt}$			
Laplace transform			
$V(s) = L[sI(s) - i(0^{+})]$			
$V(s) = LsI(s) - Li(0^{+})$	nce 1	995	
28. In a series R-L circuit, R is 10Ω and L is 2	20mH, it	f the circuit c	urrent is 10 sin 314 tA, the phase
angle θ between v and i will be			
(a) $\tan^{-1}(0.2\pi)$ (b) $\tan^{-1}(0.4\pi)$	(c)	$\tan^{-1}(0.6\pi)$	(d) $\tan^{-1}(0.8\pi)$
28. Ans: (a) Sol: $10\Omega \ 20mH$ \swarrow $V(t) = 10 \sin 314t$			
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Phase angle
$$\phi = \tan^{-1} \left(\frac{\omega L}{R} \right) = \tan^{-1} \left(\frac{314 \times 20 \times 10^{-3}}{10} \right)$$

= $\tan^{-1} (0.2 \times 3.14)$
= $\tan^{-1} (0.2 \pi)$

ACE

29. A 4Ω resistor is connected in series with a 10 mH inductor, across a 100V, 50Hz voltage source. The impedance of the circuit will be

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(a)
$$5 - j3.14$$
 (b) $5 + j3.14$ (c) $4 - j3.14$ (d) $4 + j3.14$
29. Ans: (d)
Sol: $X_L = \omega L$
 $= 2\pi f L$
 $Z = R + j X_L$
 $X_L = 2\pi (50) (10) \times 10^{-3} = \pi = 3.14$
 $Z = (4 + j3.14)\Omega$

30. A 100V, 50Hz a.c. supply is applied across a series RLC circuit having $R = 10\Omega$, L = 100 mH and $C = 1000\mu$ F. The current through the circuit will be

(a)
$$4.33 \le -70.5^{\circ} A$$

(b) $3.33 \le -70.5^{\circ} A$
(c) $2.33 \le -50.5^{\circ} A$
(d) $1.33 \le -50.5^{\circ} A$
(e) $3.33 \le -70.5^{\circ} A$
(f) $1.33 \le -50.5^{\circ} A$
(g) $1.33 \le -50.5^{\circ} A$
(h) $1.33 \le -50.5$

ACE Engineering Publications

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$$Z = 10 + j \left(10\pi - \frac{10}{\pi} \right) = 29.9 \angle 70.5^{\circ}$$
$$|Z| = 29.9 = 29.9 \angle 70.5^{\circ}$$
$$I = \frac{V}{Z} = \frac{100 \angle 0^{\circ}}{29.9 \angle 70.5^{\circ}}$$
$$I = 3.33 \angle -70.5^{\circ} \text{ A}$$

31. If any root of the characteristic equation has a positive real part or if there is a repeated root on the $j\omega$ -axis, then the system is

- (a) Limitedly stable (b) Conditionally stable
- (c) Stable (d) Unstable

31. Ans: (d)

Sol: For positive real part of roots (or) repeated roots on $j\omega$ -axis, the system is unstable.

32. The angle of departure from a real open-loop pole and the angle of arrival at a real open-loop zero is always equal to

(a) 0° only (b) 90° only (c) 180° only (d) 0° or 180°

- 32. Ans: (d)
- Sol: The angle of departure of a real pole and the angle of arrival of a real zero is equal to 0° or 180°.

Since 1995

- 33. The important aspects in the study of feedback systems are to control
 - 1. Sensitivity
 - 2. Effect of an internal disturbance
 - 3. Distortion in a nonlinear system
 - (a) 1 and 2 only (b) 1 and 3 only (c) 2 and 3 only (d) 1, 2 and 3
- 33. Ans: (d)
- **Sol:** Main aim of feedback control system (-ve feedback) is to desensitize the forward path parameter such that the overall output is insensitive to internal disturbance and to improve linearity of the system.

	Engineering Fublications	18		ESE_20 Ques	stions with Solutions
34.	In a type-1, second-order system, the first u	ndersh	oot occurs a	t a time t (with	n standard notations) i
	(a) $\frac{\pi}{\omega_{d}}$ (b) $\frac{2\pi}{\omega_{d}}$	(c)	$\frac{\pi}{2\omega_d}$		(d) $\frac{2\omega_{\rm d}}{\pi}$
34.	Ans: (b)				
Sol:	$t_p = \frac{2\pi}{\omega_d} \sec$				
35.	The compensator required to improve the st	eady s	state response	e of a system i	S
	(a) Lag (b) Lead	(c)	LAg-lead		(d) Zero
35.	Ans: (a)				
Sol:	Lag compensator improves steady state perfe	orman	ce. A		
	Len -		~~~		
36.	Which one of the following types of control	ller is s	sometimes ca	alled automati	c reset?
	(a) Proportional (b) Integral	(c)	Derivative		(d) PID
36.	Ans: (b)				
Sol:	Integral controller is called reset controller.			>\	
37.	The transfer time T of the disk is				1
	(a) $\frac{2b}{rN}$ (b) $\frac{rb}{N}$	(c)	rN b		(d) $\frac{b}{rN}$
	Where: $b =$ Number of bytes to be transfer	red	770		
	N = Number of bytes on a track				
	r = Rotation speed in rps				
37.	Ans: (d)				
Sol:	Rotation speed:				
	* r Revolutions in one second then one revol	lution	$ \frac{1}{r} $ second		
	Data Transfer Rate (DTR) = $\left(\frac{\text{Number of by}}{\text{one revolution}}\right)$	rteson ition ti	$\frac{\text{a track}}{\text{me}}$		

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 $DTR = \frac{N \text{ bytes}}{1/r \text{ sec ond}} = Nr \text{ bytes}/\text{ sec}$ Transfer time (T) = $\left(\frac{\text{Number of bytes to be transferred}}{\text{DTR}}\right)$ $T = \frac{b \text{ bytes}}{\text{Nr bytes/sec}} = \frac{b}{\text{Nr}} \text{sec}$ A core of processor chip consists of 38. 1. ALU 2. Instruction logic 3. Load/store logic 4. L3 cache 5. L1 data cache (a) 1, 2, 3 and 4 only (b) 1, 2, 3 and 5 only (c) 2, 3, 4 and 5 only (d) 1, 4 and 5 only **38.** Ans: (b) Sol: $* L_1$ (Level-1) cache memory usually built onto the microprocessor chip itself * L_2 and L_3 cache are external cache Which of the following will cause internal interrupt to CPU? 39. 1. Stack overflow 2. Attempt to divide by zero 3. I/O device finished transfer of data 4. Power failure (a) 1 and 2 only (b) 2and 3 only (c) 3 and 4 only (d) 1 and 4 only 39. Ans: (a) Sol: Internal interrupts to CPU are called traps or exceptions Stack overflow and divide by zero are run time exceptions

Power failure and I/O devices causes external interrupt

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ESE_20 Questions with Solutions

40. In an assembly language program

END

- is a/an
- (a) Machine instruction
- (c) Micro instruction
- (b) Pseudo instruction

(b) USB storage

(d) Micro-program memory

(d) Interrupt

40. Ans: (b)

Sol: END is Pseudo instruction, declare end of an assembly program

Pseudo instructions are special commands to the assembler about the positioning of the program

- Booth algorithm is associated with 41.
 - (a) Binary division
 - (b) Binary integer multiplication
 - (c) Sorting binary integers
 - (d) Searching of binary data

41. Ans: (b)

- Sol: Booth algorithm is associated with Binary integer multiplication
- The memory that communicates directly with CPU is called 42.
 - (a) Auxiliary memory
 - (c) Main memory
- 42. Ans: (c)
- Sol: Main memory communicates directly with CPU
- Virtual memory is normally implemented by 43.
 - (a) Demand paging (b) Buses
 - (c) Device drivers (d) Bus matrix
- 43. Ans: (a)
- **Sol:** Virtual memory is commonly implemented by demand paging



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	ACE Engineering Publications	22	ESE_20 Que	estions with Solutions	
44.	Which of the following are the computer memory performance parameters?				
	1. Access time (Latency)				
	2. Memory cycle time				
	3. Transfer rate				
	(a) 1 and 2 only (b) 1 and 3 only		(c) 2 and 3 only	(d) 1, 2 and 3	
44.	Ans: (d)				
Sol:	The computer memory performance param	eters a	are Access time, memory	cycle time & Transfer	
	rate				
45.	What are the components of a memory man	ageme	ent unit		
	1. A facility for dynamic storage relocation	EKIN	GAC		
	2. Provision for preventing users for sharing	g prog	cams stored in memory by	different users	
	3. Protection of information against unauthor	orized	access 2	A	
	4. Provision for users for changing operating	g syste	em functions		
	(a) 1 and 3 only (b) 1 and 4 of	only	(c) 2 and 3 only	(d) 2 and 4 only	
45.	Ans: (a)				
46.	Which one of the following makes permane	ntly re	ecorded transaction in the	database?	
	(a) View (b) Commit		(c) Roll back	(d) Flash back	
46.	Ans: (b) Since	ce 1	995		
Sol:	Commit is used to commit the transaction				
47.	The advantage of optimistic locking is				
	(a) The lock is obtained only after the transa	action	has processed		
	(b) The lock is obtained only before the tran	isactio	n has processed		
	(c) The lock never needs to the obtained				
	(d) The lock transaction are best suited with	a lot	of activity		
47.	Ans: (a)				
Sol:	The advantage of optimistic locking is the lo	ock is o	obtained only after the tran	nsaction has processed	

	ACE	23		E & T Engineering	
48.	The ability to query information from the da	The ability to query information from the database, insert, delete and modify the tuples is			
	(a) Data Definition Language (DDL)	(b)	Data Manipulatio	n Language (DML)	
	(c) Storage Definition Language (SDL)	(d)	Relational Schem	a	
48.	Ans: (b)				
Sol:	Insert, delete & modify tuples comes under	Data n	nanipulation langu	age	
49.	In a pair of straight parallel bus bars of circu	ular cr	oss-section spaced	23 cm between centres, each	
	carry a current of 70,000 A. The force requi	red to	withstand will be	nearly	
	(a) 4,800 N/m (b) 4,620 N/m	(c)	4,440 N/m	(d) 4260 N/m	
49.	Ans: (d)	DIN			
Sol:	Force between two parallel conductors,		AC		
	$F = \frac{\mu_0}{2\pi} \times \frac{I_1 I_2}{d}$	4	TO FR.		
	$=\frac{4\pi \times 10^{-7}}{2 \times \pi} \times \frac{70000 \times 70000}{23 \times 10^{-2}}$				
	= 4260.86 N/m				
50.	Consider the following two points				
	M (2, 5, -3) and N (-3, 1, 4)				
	The distance from the origin to the mid-point	nt of tł	ne line MN will be	nearly	
	(a) 3.1 units (b) 2.3 units	(c)	1.5 units	(d) 0.7 units	
50.	Ans: (a)				
Sol:	Given: M(2, 5, -3) to N (-3, 1, 4)				
	midpoint $\left(\frac{2-3}{2}, \frac{5+1}{2}, \frac{-3+4}{2}\right) = (-0.5, 3, -0.5)$	0.5)			
	distance from (0,0,0) to (-0.5, 3, 0.5)				
	$d = \sqrt{(-0.5)^2 + (3)^2 + (0.5)^2}$				
	d ≈3.1 units				

	ACE	24		ESE_20 Questions with Solutions
51.	Consider $\vec{D} = 10x\bar{a}_x - 4y\bar{a}_y + kz\bar{a}_z\mu C/m^2$ and	d \overrightarrow{B}	$=2\overrightarrow{a}_{y}$ mT, t	o satisfy the Maxwell's equation for
	region $\sigma = 0$ and $\rho_v = 0$, the value of k will be	e		
	(a) $-8 \ \mu\text{C/m}^3$ (b) $-6 \ \mu\text{C/m}^3$	(c)	$-4 \ \mu C/m^3$	(d) $-2 \ \mu C/m^3$
51.	Ans: (b)			
Sol:	Given: $\vec{D} = 10x\hat{a}_x - 4y\hat{a}_y + kz\hat{a}_z \mu C/m^2$			
	For the charge-free ($\rho_v = 0$) medium,			
	Maxwell's equation , $\nabla . \vec{D} = 0$			
	$\frac{\partial D_x}{\partial x} + \frac{\partial D_y}{\partial y} + \frac{\partial D_z}{\partial z} = 0$	DIA		
	$\Rightarrow 10 - 4 + k = 0$	EX LIP	"GAC	
	$\therefore k = -6 \ \mu C/m^3$		~~<	
	र र			32
52.	A 4-pole, wave wound armature having 45 sl	ots v	vith 18 cond	uctors/slot is driven at 1200 rpm. If
	the flux per pole is 0.016 Wb, the generated e	emf v	vill be	
	(a) 534.4 V (b) 526.8 V	(c)	518.4 V	(d) 502.8 V
52.	Ans: (c)			
Sol:	$P = 4, S = 45$ $Z = 45 \times 18 = 810$			
	(wave) Z = 18rad/slot			
	N = 1200 rpm Sinc	e 1	995	
	$\phi = 0.016 \text{ Wb}$			
	$Eg = \frac{\phi ZNP}{60A} = \frac{(0.016)(810)(1200)4}{60 \times 2}$			
	= 518.4V.			

53. For a terminated uniform transmission line, the impedance Z_x at a distance x from the load will be

(a) $Z_0 \frac{Z_L + Z_0 \tanh \gamma x}{Z_0 + Z_L \tanh \gamma x} \Omega$ (b) $Z_L \frac{Z_L + Z_0 \tanh \gamma x}{Z_0 + Z_L \tanh \gamma x} \Omega$ (c) $Z_0 \frac{Z_L + jZ_0 \tanh \gamma x}{Z_0 + jZ_L \tanh \gamma x} \Omega$ (d) $Z_L \frac{Z_L + jZ_0 \tanh \gamma x}{Z_0 + jZ_L \tanh \gamma x} \Omega$

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Where: $Z_0 =$ Characteristic impedance of line, Ω

- Z_L = Load impedance, Ω
- γ = Propagation constant = α + j β , m⁻¹
- α = Attenuation constant, Np m⁻¹
- β = Phase constant, rad m⁻¹

53. Ans: (a)

Sol: On a long transmission line the impedance at any position 'x' from the load is given by

$$Z(\mathbf{x}) = Z_0 \left(\frac{Z_{\rm L} + Z_0 \tan h\gamma \mathbf{x}}{Z_0 + Z_{\rm L} \tan h\gamma \mathbf{x}} \right) \Omega$$

54. The depth of penetration δ of a plane electromagnetic wave incident normally on a good conductor is

(a)
$$\frac{1}{\sqrt{2\pi f\mu\sigma}}$$
 (b) $\frac{1}{\sqrt{\pi f\mu\sigma}}$
(c) $\frac{2}{\sqrt{3\pi f\mu\sigma}}$ (d) $\frac{2}{\sqrt{\pi f\mu\sigma}}$

Where: f = Frequency in Hz

 σ = Conductivity in Siemens per meter

54. Ans: (b)

Sol: In a good conductor, the attenuation constant ' α ' is given by

$$\alpha = \sqrt{\frac{\omega\mu\sigma}{2}}$$

Skin depth (or) depth of penetration is of plane em wave is given by

$$\delta = \frac{1}{\alpha} = \sqrt{\frac{2}{\omega\mu\sigma}}$$

(or)

$$\delta = \frac{1}{\sqrt{\pi f \mu \sigma}}$$

ACE	26	ESE_20 Questions with Solutions
Engineering Publications		

A rectangular waveguide is 5.1 cm by 2.4 cm (inside measurement). The cutoff frequency of the 55. dominant mode will be nearly

(a) 5.38 GHz	(b) 4.54 GHz
(c) 3.78 GHz	(d) 2.94 GHz

55. Ans: (d)

Sol: Given: wave guide dimension,

a = 5.1 cmb = 2.4 cm

Cut off frequency of dominant mode is given by

$$f_{c}(TE_{10}) = \frac{c}{2a} = \frac{3 \times 10^{10}}{2 \times 5.1}$$

 $\approx 3 \text{ GHz (or) } 2.94 \text{ GHz}$

If aperture efficiency is 70%, the directivity D of a parabolic dish antenna as a function of its 56. radius is

(a)
$$20\left(\frac{r}{\lambda}\right)^2$$

(b) $28\left(\frac{r}{\lambda}\right)^2$
(c) $36\left(\frac{r}{\lambda}\right)^2$
(d) $44\left(\frac{r}{\lambda}\right)^2$
Sol: $G = \frac{4\pi}{\lambda^2} \eta A$
 $= \frac{4\pi}{\lambda^2} \times 0.7 \times \pi r^2$
 $= 4 \times 0.7 \times \pi^2 \times \left(\frac{r}{\lambda}\right)^2$
 $\approx 28\left(\frac{r}{\lambda}\right)^2$

	ACE Engineering Publications	27		E & T Engineering			
57.	An antenna radiates isotropically over a ha	lf-spac	e above a perfectly	v conducting flat ground plane.			
	If $E = 50 \text{ mV m}^{-1}$ rms at a distance of 1 km	n and th	e antenna termina	l current I = 3.5 A, the			
	radiation resistance will be						
	(a) 3.4Ω (b) 4.3Ω	(c)	5.2 Ω	(d) 6.1 Ω			
57. A	Ans: (a)						
Sol:	Given :						
	$E_{rms} = 50 \text{ mV/m}$						
	r = 1km						
	I = 3.5A						
	Average poynting vector $S_{avg} = \frac{E_{rms}^2}{\eta_0} = \frac{(50)}{\eta_0}$	$\times 10^{-3}$)	IG AC				
	Power radiated above the conducting flat g	round	plane is				
	$P_{rad} = \oint \overline{S}_{avg} \cdot \overline{dA}$		3				
	$\therefore P_{\rm rad} = \int_{\theta=0}^{\pi/2} \int_{\phi=0}^{2\pi} S_{\rm avg} r^2 \sin \theta d\theta d\phi$	1					
	$= \int_{\theta=0}^{\pi/2} \int_{\phi=0}^{2\pi} \frac{(50 \times 10^{-3})^2}{120\pi} \times (1 \times 10^3)^2 \sin \theta d\theta d\phi$						
	$=\frac{(50)^2}{120\pi}\left(-\cos\theta\Big _0^{\pi/2}\right)\left(\phi\Big _0^{2\pi}\right)$	ce 1	995				
	$=\frac{(50)^2}{120\pi}\times(1)\times(2\pi)$		E				
	$P_{rad} = \frac{(50)^2}{60}$						
	\therefore Power radiated $P_{rad} = I^2 R_{rad}$						
	$\therefore R_{rad} = \frac{P_{rad}}{I^2}$						
	$\therefore R_{rad} = \frac{(50)^2}{60(3.5)^2} = 3.4\Omega$						

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58. Which one of the following is the correct relationship between an antenna gain G and an effective area A_e?

(a)
$$G = \frac{4\pi f^2 A_e}{c^2}$$
 (b) $G = \frac{3\pi f^2 A_e}{c^2}$ (c) $G = \frac{2\pi f^2 A_e}{c^2}$ (d) $G = \frac{0.5\pi f^2 A_e}{c^2}$

Where: f = Carrier frequency

c = Speed of light

58. Ans: (a)

Sol: The directive gain 'G' and effective area of antenna is given by

$$\mathbf{G} = \left(\frac{4\pi}{\lambda^2}\right) \mathbf{A}$$

Let $\lambda = \frac{c}{f}$

$$G = \frac{4\pi f^2}{c^2} A_e$$

59. The signal-to-noise ratio $\frac{S}{N}$ for isotropic antenna is

(a)
$$\frac{\lambda^2}{16\pi^2 r^2 k T_{sys} B}$$
 (b) $\frac{\lambda^2}{14\pi^2 r^3 k T_{sys} B}$ (c) $\frac{\lambda^2}{12\pi^2 r^4 k T_{sys} B}$ (d) $\frac{\lambda^2}{10\pi^2 r^4 k T_{sys} B}$

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Where: $\lambda =$ Wavelength, m

r = Distance from transmitter to receiver, m

 $T_{sys} = System temperature, K$

B = Bandwidth, Hz

k = Boltzmann's constant

59. Ans: (a)

Sol: The SNR for an isotropic antenna is given as

$$SNR = \frac{power received}{kT_{sys}B} = \frac{P_tG_tG_r\lambda^2}{(4\pi R)^2 kT_{sys}B} = \frac{\lambda^2}{(4\pi R)^2 kT_{sys}B}$$

For isotropic antenna Pt=1, Gt=1,Gr=1

$$\therefore \text{ SNR} = \frac{\lambda^2}{16\pi R^2 k T_{\text{sys}} B}$$











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				1	
	ACE Engineering Publications		30	ESE	_20 Questions with Solutio
60.	Consider a cube define	d by			
	x, y, $z = [1, 3]$				
	If vector, $A = 2x^2ya_x + $	$3x^2y^2a_y$,			
	$\vec{V.A}$ at the centre of the	e cube will be			
	(a) 72	(b) 64	(b)	60	(c) 48
60. A	Ans: (b)				
Sol:	Given: $\vec{A} = 2x^2y\hat{a}_x + 3x$	$x^2y^2\hat{a}_y$			
	Cube: x,y,z∈ [1,3]				
	$\nabla \vec{A} = 4xy + 6x^2y$		RIA		
	$\nabla \vec{A}$ at the center of the	e cube i.e. at x,y,z=2		ACA	

 $\nabla \vec{A} = 4(2)(2) + 6(2)^2(2) = 16 + 48 = 64$

61. Which of the following steps are followed by HIS during synthesis?

- 1. Data model generation
- 2. Data flow analysis
- 3. Scheduling and allocation
- 4. Data path optimization
- 5. Control optimization
- (a) 1, 3 and 5 only
- (b) 2, 4 and 5 only
- (c) 1, 2, 3 and 4 only
- (d) 1, 2, 3, 4, and 5

61. Ans: (a)

- Sol: The steps followed by HIS during synthesis are
 - 1. Data Model generation
 - 3. Scheduling and allocation
 - 5. Control optimization

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		31	E & T	Engineering
62.	Pipelining			

1. Reduces clock period of long combinational operations

2. Allows large combinational functions to be broken down into pieces whose delays are balanced with the rest of the system components

(a) 1 only (b) 2 only (c) Both 1 and 2 (d) Neither 1 nor 2

62. Ans: (c)

- **Sol:** Pipelining reduces clock period of long combinational operations & allows large combinational functions to be broken down into pieces whose delays are balanced with the rest of the system components
- 63. Superscalar processor consists of
 - (a) Single pipeline for instruction execution
 - (b) Multiple-instruction pipelines for instruction execution
 - (c) No pipelines for instruction execution
 - (d) Multiple combination of hardware for execution

63. Ans: (b)

- Sol: Superscalar processors consists of multiple-instruction pipeline for instruction execution
- 64. Which of the following statements is/are correct?
 - 1. In hybrid parameter representation, both short and open circuit terminal conditions are utilized.

2. The voltage of output port and the current of input port are expressed in terms of current of output and voltage of input port.

- (a) 1 only (b) 2 only (c) Both 1 and 2 (d) Neither 1 nor 2
- 64. Ans:(a)
- Sol: 1. Hybrid parameters

$$V_1 = h_{11}I_1 + h_{12}V_2$$

$$I_2 = h_{21}I_1 + h_{22}V_2$$

Dependent variables

2. g-parameters

$$\label{eq:II} Independent variables \\ I_1 = g_{11}V_1 + g_{12} I_2 \\ V_2 = g_{21}V_1 + g_{22}I_2 \\ Dependent variables \\ \end{array}$$

- 65. Consider the following measurements on a two terminal network:
 - 1. When a voltage of $100 \angle 0^{\circ}$ volts applied at input port with output port open, $I_1 = 20 \angle 0^{\circ}$ A and

$$V_2 = 25 \angle 0^{\circ} V$$

2. When a voltage of $100 \angle 0^\circ$ volts applied at output port with input port open, $I_2 = 10 \angle 0^\circ$ A and $V_1 = 50 \angle 0^\circ$ V

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The driving point impedances Z₁₁, Z₂₂ and transfer impedances Z₂₁, Z₁₂ respectively are

- (a) 5 Ω , 10 Ω and 1.25 Ω , 5 Ω
- (b) 10 Ω , 5 Ω and 1.25 Ω , 5 Ω
- (c) 5 Ω , 1.25 Ω and 5 Ω , 10 Ω
- (d) 10 Ω , 1.25 Ω and 5 Ω , 5 Ω
- 65. Ans: (a)

Sol: 1. $V_1 = 100 \angle 0^\circ$, $I_1 = 20 \angle 0^\circ A$, $V_2 = 25 \angle 0^\circ$ when $I_2 = 0$

$$Z_{11} = \frac{V_1}{I_1} = \frac{100}{20} = 5\Omega$$
$$Z_{21} = \frac{V_2}{I_1} = \frac{25}{20} = 1.25\Omega$$

2. $V_2 = 100 \angle 0^\circ$, $I_2 = 10A$, $V_1 = 50 \angle 0^\circ$ when $I_1 = 0$

$$Z_{22} = \frac{100 \angle 0^{\circ}}{10 \angle 0^{\circ}} = 10\Omega \left(\frac{V_2}{I_2}\right)$$

$$Z_{12} = \frac{V_1}{I_2} = \frac{50 \angle 0^{\circ}}{10 \angle 0^{\circ}} = 5\Omega$$

 $Z_{11} = 5\Omega, Z_{22} = 10\Omega, Z_{21} = 1.25\Omega, Z_{12} = 5\Omega$

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	ACE Engineering Publications	33	E&T Engineering	
66.	In a second order digital notch filter having	notch	frequency of 60 Hz and a 3-dB notch bandwidth	
	of 6 Hz and sampling frequency employed	is 400	Hz. The normalized angular notch frequency ω_0	
	and the normalized angular 3-dB bandwidth	$\Delta \omega_{3dI}$	3 are	
	(a) 0.3π and 0.03π (b) ().6π aı	nd 0.03π	
	(c) 0.3π and 0.06π (d) ().6π aı	nd 0.06π	
66.	Ans: (a)			
Sol:	notch frequency = 60 Hz 3dB	notch	BW = 6Hz	
	\mathbf{f}_0	f _s =	= 400Hz	
	Normalised angular notch frequency $\omega_0 = \frac{2}{4}$	$\frac{2\pi f_0}{f_s} = \frac{20\pi}{400}$	$=\frac{2\pi(60)}{400}$ $=\frac{3\pi}{10}=0.3\pi$	
	normalised angular 3-dB B.W		E Start	
	$\Delta \omega_{3\text{dB}} = \frac{2\pi(6)}{400} = \frac{12\pi}{400} = \frac{3\pi}{100} = 0.03\pi$			
67	The two channel bank with multirate digit	al filt	er structure that employs two decimators in the	
07.	7. The two channel bank with multirate digital filter structure that employs two decimators in the signal analysis section and two interpolators in the signal synthesis section is called			

- (a) Multirate signal processing bank
- (b) Sub-coding and analysis bank
- (c) Sub-band speech coder bank
- (d) Quadrature mirror filter bank



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55 20					
	Engineering Publications	34	ESE_20 Questions with Solutions		
68.	Which of the following are the advantages of	ages of digital filters over analog filters?			
	1. Highly flexible				
	2. Portable				
	3. Negligible noise interference				
	4. Lumped RLC components				
	(a) 1,2 and 3 only (b) 1	,2 and	l 4 only		
	(c) 1,3 and 4 only (d) 2	.,3 and	l 4 only		
68.	Ans: (a)				
69.	The realization of a length M FIR filter for	or a l	inear phase structure, the number of multipliers		
	required is		NG AC		
	(a) $\left[\frac{M+1}{2}\right]$ (b) 2M	4	(c) M (d) M – 1		
69.	Ans: (a)				
Sol:	: To realise a length M FIR filter for a linear phase structure, the number of multipliers required is				
	$\frac{M+1}{2}$ for odd length				
	$\frac{M}{2}$ + 1 for even length				
-	Since	ce 1	995		
/0.	Which one of the following statements is not correct regarding a usage of virtual memory?				

(a) To free user programs from the need to carryout storage allocation and to permit efficient sharing of the available memory space among different users

(b) To make program independent of the configuration and capacity of the physical memory for their execution.

- (c) to achieve higher CPU performance
- (d) To achieve the very low access time and cost per bit that is possible with a memory hierarchy

70. Ans: (c)

Sol: Virtual memory is not used to improve CPU performance. It is used for memory management to run larger programs with small memory.

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- 71. In the 8051 microcontroller, direct addressing mode is used in
 - (a) Internal data memory (b) External data memory
 - (c) Internal program memory
- (d) External program memory

71. Ans: (a)

Sol: Direct addressing mode is only used for internal RAM [i.e., internal data memory] Eg:- MOV A, 30H

72. PUSH and POP operations are performed by

- (a) Program counter register
- (b) General purpose register
- (c) Stack pointer register
- (d) Link register

72. Ans: (c)

- Sol: PUSH and POP operations are performed by stack pointer register.
- 73. Network Interface Card (NIC) has a unique six-byte permanent address as

(a) IP address			(b) MAC address
----------------	--	--	-----------------

(c) DNS address

73. Ans: (b)

Sol: The MAC address is a six-byte number or 12-digit hexadecimal number that is used to uniquely identity a host on a network.

(d) Local address

- 74. The data-link layer is responsible for
 - (a) Incoming bit stream and simply repeats to other devices connected
 - (b) An error free communication across the physical link connecting primary and secondary stations within a network
 - (c) An end-to-end integrity of data message propagated through the network between two devices
 - (d) Logical connection at application layer

74. Ans: (b)

Sol: In HDLC, primary to secondary using Hub polling. HDLC is an example for data link layer
Engineering Publications	36	ESE_20 Questions with Solutions
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- 75. The transmit carrier frequency f_t and receive carrier frequency f_r for AMPS channels-3 are nearly
 - (a) 875 MHz and 870 MHz (b) 825 MHz and 870 MHz
 - (c) 875 MHz and 830 MHz (d) 825 MHz and 830 MHz

75. Ans: (b)

Sol: The mobile transmit frequency $f_t = (0.03N + 825)$ MHz

 $f_t = (0.09 + 825) \text{ MHz}$

 $f_r = f_t + 45 MHz$

for channel 3

- $f_t = 825.09 MHz$
- $f_r = 870.09 MHz$
- 76. Which one of the following mode is called a two-way simultaneous, communication between two stations ?
 - (a) Simplex (SX)
 - (b) Half duplex (HDX)
 - (c) Full duplex (FDX)
 - (d) Full/Full duplex (F/FDX)

76. Ans: (c)

Sol: In full duplex mode, both stations can transmit and receive simultaneously.

Since 1995

- 77. Blocked calls may be handled in one of two ways. First blocked calls can be put in a queue awaiting a free channel. This is termed as
 - (a) Lost Calls Cleared (LCC)
 - (b) Lost Calls Delayed (LCD)
 - (c) Lost Calls Held (LCH)
 - (d) Lost Calls Hand off
- 77. Ans: (b)
- **Sol:** Blocked calls may be handled in one of two ways. First blocked calls can be put in a queue awaiting a free channel is called as lost calls delayed. Although, in fact the call is not lost merely delayed. Second it can be rejected & dropped





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Exam Date : 23 rd February 2020 @ 11:00 AM No. of Questions: 50 (1M:25, 2M:25) Marks : 75 Duration : 90 Min. Streams : EC EE ME CE CSIT IN PI				* Al based proctor * Test can be written	ing exa	Mo Mo minatic where b	ode of Exa	m Ler (Desk	ettop or Laptop) and Wel	Dcam.
Engg. Mathematics : 20 Q Numerical Ability : 20 Q Verbal Ability : 10 Q										
	ļ	Syllabus for 3rd/4	4 th Yea	r & Passed-out	Stude	ents - '	Technical I	Paper	,	
EEE		ECE / IN		CS & IT			CE		ME / PI	
Subject	No. of Questions	Subject	No. of Questions	Subject	No. of Questions	S	Subject	No. of Questions	Subject	No. of Questions
Networks	5 Q	Networks	6 Q	DS,PL& Algorithm	10 Q	SOM		5 Q	SOM	6 Q
Control System	5 Q	Control System	6 Q	DBMS	5 Q	FM&H	ΗM	5 Q	FM & HM	5 Q
Analog Electronics	4 Q	Analog Electronics	5 Q	Computer Networks	5 Q	Geo Te	chnical Engg.	7 Q	ТОМ	6 Q
Digital Electronics	5 Q	Digital Electronics	5 Q	Operating System	6 Q	Enviro	nmental	7 Q	Machine Design	4 Q
Electrical Machines	8 Q	Signal & Systems	5 Q	Computer Organization	4 Q	Transp	oortation	4 Q	Thermal	7 Q
Power System	7 Q	EDC & VLSI	5 Q	Theory of Computation	6 Q	RCC&	STEEL	6 Q	Heat Mass Transfer	4 Q
Power Electronics	6 Q	Communications	8 Q	Digital Electronics	4 Q	Surve	ying	6 Q	Production	8 Q
Engg. Maths	5 Q	Engg. Maths	5 Q	Engg. Maths	5 Q	Engg.	Maths	5 Q	Engg. Maths	5 Q
Numerical / Verbal Ability	5 Q	Numerical / Verbal Ability	5 Q	Numerical / Verbal Ability	5 Q	Numeric	al / Verbal Ability	5 Q	Numerical / Verbal Ability	5 Q
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(The above given positions should achieve Min. 50% of marks in the test).

IMPORTANT DATES : Registrations Start from : 8th December 2019, End Date: 14th February 2020 | Exam Date: 23th February 2020









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- 78. Satellite communication among stations in different areas can be achieved if the satellite has the ability to switch time slots from one beam to another. This is known as satellite switched
 (a) TDMA
 (b) TSMA
 (c) FAMA
 (d) SCPC
- 78. Ans: (a)
- 79. A coherent binary phase shift keyed (BPSK) transmitter operates at a bit rate of 20 Mbps. For a probability of error P(e) of 10^{-4} , the ratio $\frac{C}{N} = 8.8 dB$, the minimum theoretical $\frac{E_b}{N_o}$ ratio for a

(b) 6.4 dB

(d) 10.4 dB

receiver bandwidth equal to the minimum double-sided Nyquist bandwidth will be

- (a) 4.8 dB
- (c) 8.8 dB
- 79. Ans: (c)
- Sol: With BPSK, the minimum BW is equal to the bit rate 20 MHz. The minimum $\frac{C}{N}$ is 8.8dB for a
 - $P_e = 10^{-4}$

$$\left(\frac{E_{b}}{N_{0}}\right) dB = \left(\frac{C}{N}\right) dB + \left(\frac{BW}{R_{b}}\right) dB$$

$$\left(\frac{\mathbf{E}_{b}}{\mathbf{N}_{0}}\right)\mathbf{dB} = \left(\frac{\mathbf{C}}{\mathbf{N}}\right)\mathbf{dB} = 8.8\mathbf{dB}.$$

For a total transmit power (Pt) of 1000W and for a transmission rate of 50 Mbps, the energy per bit (Eb) will be

Since 1995

- (a) $10 \ \mu J$ (b) $20 \ \mu J$ (c) $30 \ \mu J$ (d) $40 \ \mu J$
- 80. Ans: (b)

Sol: $P_t = 1000W$

 $R_b = 50 \text{ Mbps}$

$$E_{b} = \frac{1000}{50 \times 10^{6}} = 20 \mu J$$

	ACE Engineering Publications	39	E&T Engineering					
81.	A combination of direct sequence and frequency hopping is called							
	(a) Direct sequence hopping	(a) Direct sequence hopping						
	(b) Hybrid direct frequency hopping							
	(c) Direct sequence frequency hopping							
	(d) Hybrid direct sequence frequency hopping	ng						
81.	Ans: (d)							
Sol:	Combination of direct sequence and frequen	ncy ho	pping is called as Hybrid Direct sequence					
	frequency hopping							
82.	Each earth station's transmission is encoded	with a	a unique binary word called					
	(a) Station code (b) Chip code (b)	(c)	Access code (d) Gold code					
82.	Ans: (b)		AD.					
Sol:	Each station has a unique chip code. To rec	eive a	a particular earth stations transmission, a receiver					
	station must know the chip code for that stat	ion.						
83.	For a 300 m optical fibre cable with BLP of	600 N	Hz-km, the bandwidth will be					
	(a) 8 GHz (b) 6 GHz	(c)	4 GHz (d) 2 GHz					
83.	Ans: (d)							
Sol:	$BLP = 600 \times 10^6 \text{ Hz}-\text{Km}.$							
	L = 300m = 0.3Km							
	$BW = \frac{BLP}{L} = \frac{600 \times 10^6}{0.3} = 2GHz$ Since	ce 1	995					
84.	Numerical aperture (NA) in optical fibre tra	ismiss	sion is used to describe					

- (b) Light gathering or light collecting ability
- (c) Light output from external shield
- (d) Light leakage ability

84. Ans: (b)

Sol: Numerical aperture indicates the light gathering capacity of a optical fibre.

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Directions:

Each of the next Six(06) items consists of two statements, one labelled as the 'Statement (I)' and the other as 'Statement (II)'. You are to examine these two statements carefully and select the answers to these items using the codes given below:

Codes:

(a) Both Statement (I) and Statement (II) are individually true and Statement (II) is the correct explanation of Statement (I)

(b) Both Statement (I) and Statement (II) are individually true but Statement (II) is **NOT** the correct explanation of Statement (I)

(c) Statement (I) is true but Statement (II) is false

- (d) Statement (I) is false but Statement (II) is true.
- 85. **Statement (I):** Channel vocoder (voice coder) is an analysis synthesis system **Statement (II):** For voiced signal, the excitation is a white noise and for an unvoiced signal, the excitation is a periodic signal.
- 85. Ans: (c)
- Sol: Channel vocoder is an analysis synthesis system (TRUE)

Voice signal \rightarrow excitation is periodic signal

unvoiced signal \rightarrow random noise generator

 $S_1 \rightarrow TRUE$

- $S_2 \to FALSE$
- 86. Statement (I): Control logic in CMOS is constructed using two-level SOP logic and multilevel logic.

Since 1995

Statement (II): Typical PLA uses multilevel logic.

- 86. Ans: (c)
- Sol: Statement I is true

Many functions in control logic have two-level implementation, and no. of levels grow with the number of inputs of the function.

Statement II is false

PLA is implemented as AND-OR logic which is a two-level logic.

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87. Statement (I): ABCD parameters are widely used in analysis of power transmission engineering and termed as circuit parameters.

Statement (II): ABCD parameters are called as transmission parameters.

87. Ans: (a)

- Sol: Statement (I): ABCD parameters are used in analysis of power transmission lines Statement (II): ABCD parameters are also called transmission parameters.
- 88. Statement (I): Non-stationary signals such as an image require time-frequency analysis. Statement (II): The short time Fourier transform (STFT) can map a one dimensional function f(t) into the two-dimensional function, STFT (f)

88. Ans: (a)

- Sol: Statement I: TRUE
 - Statement II: TRUE

In the continuous case, the function to be transformed is multiplied by a window function which is non-zero for only a short period of time. The F.T. of 1D function of the resulting signal is taken as window is slide of along the time axis, resulting in a 2D representation of signal

$$\mathrm{STFT}\{\mathbf{x}(t)\}(\tau,\omega) = \mathbf{X}(\tau,\omega) = \int_{-\infty}^{+\infty} \mathbf{x}(t)\omega(t-\tau)e^{-j\omega t}dt$$

 $\omega(\tau) \rightarrow$ window function

Statement (I): PCM requires a very complex encoding and quantization circuitry.
 Statement (II): PCM requires a less bandwidth compared to analog systems.

89. Ans:(c)

- Sol: PCM requires more bandwidth compared to analog systems.
- 90. Statement (I): For an unstable feed-back system, the gain margin is negative or the phase margin is positive.

Statement (II): For a stable feedback system, both gain margin and phase margin must be positive.

- 90. Ans: (d)
- Sol: For closed loop stable system, both gain margin and phase margin must be positive.



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- 91. A three-phase full wave rectifier with resistive load has ripple factor
 - (a) 0.482 (b) 1.000 (c) 0.055 (d) 0.500

91. Ans: (c)

Sol: In order to calculate the ripple factor we must extract the ac component from V₀ using the relationship: $V_{0(ac)} = \sqrt{V_{0(rms)}^2 - V_0^2}$

The Ripple factor =
$$\frac{V_{0(ac)}}{V_0} = \frac{\sqrt{V_{0(rms)}^2 - V_0^2}}{V_0} = \sqrt{\frac{V_{0(rms)}^2}{V_0^2} - 1} = \sqrt{\frac{1}{0.998} - 1} = 0.04$$
 (rectification ratio = 0.998)

- 92. If $T_A = 50^{\circ}$ C, $T_J = 200^{\circ}$ C and $\theta_{J-A} = 100^{\circ}$ C/W, the power that a transistor, 2N1701 can safely dissipate in free air will be
- (a) 0.5 W(b) 1.5 W(c) 2.5 W(d) 3.5 W92. Ans: (b) Sol: $T_A = 50^{\circ}\text{C}$ $T_j = 200^{\circ}\text{C}$ $Q_{jA} = 100^{\circ}\text{C/W}$ $T_j - T_A = Q_{JA} P_D$ $200 - 50 = 100^{\circ}\text{C/W} P_D$ Since 1995 $\frac{150}{100} = P_D$ 1.5 Watts
- 93. In a differential amplifier, there are two sets of input signals. In first set, $v_1 = +50\mu V$ and $v_2 = -50\mu V$ and in second set, $v_1 = 1,050\mu V$ and $v_2 = 950\mu V$. If the common mode rejection ratio is 100, the percentage difference in the output voltage for the two sets of input signals will be
 - (a) 10% (b) 15%
 - (c) 20% (d) 25%

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93. Ans: (a)

Sol: Case (i)

 $V_1 = 50 \mu V, V_2 = -50 \mu V$

CMRR = 100

Error in the output,
$$V_{01} = \frac{1}{CMRR} \left[\frac{V_C}{V_{id}} \right]$$
 (1)

$$= \frac{1}{100} \left[\frac{V_1 + V_2}{2} \right]$$
 (2)

$$= \frac{1}{100} [0]$$
 (3) ERING

$$= 0V$$
 (4)
Case (ii): $V_1 = 1050 \mu V$, $V_2 = 950 \mu V$ & CMRR = 100

С

Error in the output, $V_{02} = \frac{1}{100} \left[\frac{1000 \mu V}{100 \mu V} \right] = 0.1 V$ (5)

 \therefore % difference in the output voltage = (0.1V-0V) × 100 = 10 %

- 94. A linear ramp ADC uses a 10 bit counting register and a 15kHz clock frequency. The register output is 1111111111 when the input voltage is 100mV. The required ramp rate-of-change and the Since 1995 ADC conversion time are nearly
 - (b) 2.5 V/s and 90 ms (a) 1.5 V/s and 75 ms (c) 1.5 V/s and 90 ms

(d) 2.5 V/s and 75 ms

Ans: (a) **94**.

Sol: Given counter type ADC, N = 10bit; f = 15 kHz; T = $\frac{1}{15 \times 10^3}$.

The time taken to reach 1111111111 for $V_{in} = 100 \text{mV} = (2^{N} - 1)$.T

i.e, Rate of change
$$=\frac{100 \times 10^{-3}}{(2^{10}-1)T} = \frac{100 \times 10^{-3}}{1023} \times 15 \times 10^{3} = 1.5 \text{ V/s}$$

Conversion time = $(2^{N}-1)$.T = $(2^{10} -1)$.T = 68.2ms ≈ 75 ms.

	ACE Engineering Publications	45	E & T Engineering				
95.	An 8-bit DAC produces $V_{out} = 0.05V$ for a	digital	input of 00000001. The full scale output will be				
	nearly						
	(a) 12.8V	(b)	17.8V				
	(c) 22.8V	(d)	27.8V				
95.	Ans: (a)						
Sol:	8-bit ADC, step size = $0.05V$						
	Full scale output = $(2^{N}-1) \times$ step size						
	$=(2^{8}-1) \times 0.05 = 255 \times 0.05$)5					
	≈ 12.8V						
		DIA					
96.	Master Slave flip-flop is also called		GAC				
	(a) Pulse triggered flip-flop	(b)	Latch				
	(c) Level triggered flip-flop	(d)	Buffer				
96.	Ans: (a)						
Sol:	Master-slave flip-flop is also called as pulse	trigge	red flip-flop				
97.	The resolution of 6-bit DAC will be nearly						
	(a) 4.6% (b) 3.2%	(c)	1.6% (d) 1.2%				
97.	Ans: (c)						
Sol:	→ resolution = $\frac{1}{2^{N}-1} \times 100 = \frac{1}{2^{6}-1} \times 100$	ce 1	995				
	= 1.587% ≈ 1.6%						
98.	An expression $f = AB + A + AB$ can be red	uced to)				
	(a) A (b) B	(c)	0 (d) 1				
00							
90.	Ans: (c)						

 $=\overline{\overline{A}+\overline{B}+\overline{A}+B}=\overline{\overline{A}+\overline{B}+B}=\overline{\overline{1}}=0$

- 99. K-map is used to minimize the number of
 - (a) Flip-flops in digital circuits
 - (b) Layout spaces in digital circuits for fabrication
 - (c) Functions of 3,4,5 or 6 variables
 - (d) Registers in CPU

99. Ans: (c)

- Sol: K-map is used to minimize the number of functions of 3, 4, 5 or 6 variables.
- 100. A finite state machine
 - (a) is same as that of abstract model of sequential circuit
 - (b) consists of combinational logic circuits only
 - (c) contains infinite number of memory devices
 - (d) does not exist in practice

100. Ans: (a)

- **Sol:** A FSM is computational model that can be used to simulate sequential logic and control execution flow. So, FSM is same as that of abstract model of sequential circuit.
- 101. A logic circuit that accepts several data inputs and allows only one of them at a time to get through to the output is called
 - (a) Multiplexer
 - (c) Transmitter

(b) De-multiplexer(d) Receiver

- 101. Ans: (a)
- **Sol:** Multiplexer is a logic circuit that accepts several data inputs and allows only one of them at a time to get through to the output

102. The memory technology which needs the least power is

- (a) ECL (b) MOS
- (c) CMOS (d) TTL

102. Ans: (c)

Sol: CMOS memory technology needs the least power

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- 103. The mapping function that assigns a number to each outcome is called
 - (a) Sample space (b) Random variable (c) Discrete variable (d) Event

- **Sol:** A function whose domain is sample space and whose range is a set of real numbers is called as random variable of the experiment.
- 104. A device has 200 Ω equivalent noise resistance, 300 Ω input resistor and the bandwidth of the amplifier being 6 MHz. If the operating temperature of the amplifier is 290°K, the noise voltage at the input of a television RF amplifier will be nearly

(a)
$$7 \mu V$$
 (b) $5 \mu V$ (c) $3 \mu V$ (d) $1 \mu V$
104. Ans (a)
Sol: $R_{eq} = 200 + 300 = 500 \Omega$
 $V_n = \sqrt{4kTBR}$
 $k = 1.38 \times 10^{-23} J/K$
 $T = 290 K$
 $B = 6 MHz$
 $V_n = 6.93 \times 10^{-6} \approx 7 \mu V.$

(b) 0.764

- 105. When unmodulated carrier alone is transmitted, the antenna current is 9A. When sinusoidal modulation is present, the antenna current is 11A. The modulation index used will be nearly
 - (a) 0.994

(c) 0.546

(d) 0.326

- 105. Ans: (a)
- **Sol:** $I_C = 9A$

$$I_t = 11A$$
$$I_t = I_C \sqrt{1 + \frac{\mu^2}{2}}$$
$$11 = 9\sqrt{1 + \frac{\mu^2}{2}}$$

^{103.} Ans:(b)

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$$\sqrt{1 + \frac{\mu^2}{2}} = \frac{11}{9} \text{ or } 1 + \frac{\mu^2}{2} = \left(\frac{11}{9}\right)^2$$
$$\frac{\mu^2}{2} = \left(\frac{11}{9}\right)^2 - 1$$
$$\mu^2 = 2\left[\left(\frac{11}{9}\right)^2 - 1\right]$$
$$\mu = \sqrt{2\left[\left(\frac{11}{9}\right)^2 - 1\right]} = 0.994$$

106. Frequency modulated signal with single-tone modulation has a frequency deviation of 15kHz and bandwidth of 50 kHz. The frequency of the modulating signal will be

	(a) 05 kHz	(b) 10 kHz	(c) 20 kHz	(d) 30 kHz
106.	Ans: (b)	· ·		
Sol:	$\Delta f = 15 \text{ kHz}$			
	BW = 50 kHz			
	$BW = 2\Delta f + 2f_m$			
	$50k = 2 \times 15k + 2f_m$			
	$2f_m = 50k - 30k = 20k$			
	$f_m = \frac{20k}{2} = 10 kHz$	Since	1995	
	··· 2			

- 107. When the carrier and one of the sidebands are suppressed in an AM wave modulated to a depth of 50%, the power saving will be
 - (a) 84.4% (b) 88.6% (c) 94.4% (d) 98.6%
- 107. Ans:(c)

Sol: Total Power, $P_t = P_c \left[1 + \frac{\mu^2}{2} \right]$

If the carrier and one of the side band is suppressed, the power saving is $P_c + \frac{P_c \mu^2}{4}$

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108. An output of balanced modulator contains

- (a) Carrier, LSB and USB
- (b) Modulation frequency, carrier frequency and LSB
- (c) Modulation frequency, carrier frequency and USB
- (d) Modulation frequency, LSB and USB

108. Ans: (d)

- **Sol:** Balanced modulator balanced with carrier. So, the output of balanced modulator Contains modulation frequency, upper side band and lower side band components.
- 109. The temperature of a particular place varies between 14°C and 34°C. For the purpose of transmitting the temperature record of that place using PCM the record is sampled at an appropriate sampling rate and the samples are quantized. If the error in the representation of the samples due to quantization is not to exceed $\pm 1\%$ of the dynamic range, the minimum number of quantization levels that can be used will be

- (a) 40 (b) 50
- (c) 60 (d) 70

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109. Ans: (b)

Sol: Dynamic range = 34 - 14 = 20

Maximum error $= \frac{\Delta}{2}$ $\frac{\Delta}{2} = \frac{1}{100} \times 20 \implies \Delta = \frac{40}{100} = 0.4$

- $\Delta = \frac{\text{Dynamic range}}{\text{Quantization levels}} = \frac{20}{\text{L}}$
- $\frac{20}{L} = 0.4$ L = $\frac{200}{4} = 50$.
- $L = \frac{1}{4} = 30$
- 110. A telephone signal band limited to 4 kHz is to be transmitted by PCM. If the signal to quantization noise is to be at least of 40 dB, the number of levels into which the signal is to be encoded will be

(a) 32 (b) 64 (c) 81 (d) 128 **110.** Ans: (d) Sol: W = 4kHz SNR = 40dB

1.8 + 6n = 40dB

 $6n = 40 - 1.8 \Rightarrow 6n = 38.2 \Rightarrow n = \frac{38.2}{6} = 7$

$$L = 2^7 = 128$$

111. To avoid slope overload error in delta modulation, the maximum amplitude of the input signal is

ce

1995

(a)
$$A \le 2\pi f_m$$
 (b) $A \le \sin 2\pi f_m$ (c) $A \le \frac{2\pi f_m}{\Delta f_s}$ (d) $A \le \frac{\Delta f_s}{2\pi f_m}$

Sol: $\frac{\Delta}{T_s} \ge A2\pi f_m$

$$\Delta f_{s} \ge A2\pi f_{m}, \quad A \le \frac{\Delta f_{s}}{2\pi f_{m}}$$

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		I		
	ACE Engineering Publications	53		E&T Engineering
112.	If bandwidth is of primary co considered ?	ncern, which	one of the following	scheme is generally not
	(a) PSK (b) ASK	(c)) DPSK	(d) FSK
112.	Ans: (d)			
Sol:	When compared with all technique	s, non coherer	t FSK requires more bar	ıdwidth
112	The uncose of easiering to each a			e signal e discusta value
113.	fine process of assigning to each o	ne of the sam	pie values of the messag	e signal, a discrete value
	from a prescribed set of a finite num (x) Filturing (x)	nder of such a		
	(a) Filtering (b)	Noise remova	1	
110	(c) Decoding (d)	Quantization	VGA	
113.	Ans: (d)		CA	
Sol:	Quantizer assigns sample value of	the message si	gnal to a prescribed set of	it discrete value. This
	process is called "Quantization".		2	
114.	Which one of the following types o	f fiber suffers	with modal dispersion?	
	(a) Single-mode step-index fiber			
	(b) Multimode graded-index fiber			
	(c) Multimode step-index fiber			
	(d) Single-mode graded-index fiber			
114.	Ans: (c)	Since 1	005	
Sol:	Modal dispersion is the dominant s	ource of dispe	rsion in multimode fiber	s. Modal dispersion does
	not occur in single mode fibers.			-
115.	An inductor is described by input o	utput relation	as	
	$y(t) = \frac{1}{L} \int_{-\infty}^{\infty} x(\tau) d\tau$			
	The operation representing the inve	erse system x(t) will be	
	(a) $L\frac{d}{dt}y(t)$ (b)	L (c)	$\frac{\mathrm{d}}{\mathrm{dt}} \mathbf{y}(t)$	(d) Ly(t)

ACE Engineering Publications

115. Ans: (a)

Sol:
$$y(t) = \frac{1}{L} \int_{-\infty}^{t} x(\tau) d\tau \xrightarrow{LT} Y(s) = \frac{X(s)}{Ls}$$

 $X(s) = Ls Y(s)$
 $\downarrow ILT$
 $Ldy(t)$

inverse system is $x(t) = \frac{Ldy(t)}{dt}$

- 116. Step response of the system is defined as
 - 1. The output due to a unit step input signal
 - 2. The running sum of impulse response
 - 3. The running integral of impulse response for a continuous-time system
 - (a) 1 and 2 only (b) 1 and 3 only (c) 2 and 3 only (d) 1,2 and 3

116. Ans: (d)

Sol: 1. Step response is defined as the output due to unit step input

$$x(t) = u(t)$$

$$L.T.I$$

$$y(t) = s(t)$$

$$system$$

2.
$$s(n) = \sum_{k=-\infty}^{n} h(k) \rightarrow running summation of I.R$$

3.
$$s(t) = \int_{-\infty}^{t} h(\tau) \rightarrow \text{ running integral of I.R}$$

All are correct

- 117. The signal flow graph of a system is constructed from its
 - (a) Differential equations
 - (b) Algebraic equations
 - (c) Algebraic equations through the cause-and-effect relations
 - (d) Differential equations through the cause-and-effect relations

117. Ans: (c)

Sol: Signal flow graph is constructed from its linear algebraic equations through the cause-and-effect relations.

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- 118. If all the roots of the characteristics equation have negative real parts, the system is
 - (a) Stable (b) Unstable
 - (c) Marginally stable (d) Conditionally stable

118. Ans: (a)

- **Sol:** If the all the roots of characteristic equation have negative real part, then the system is stable, because the system given bounded output to bounded input.
- 119. A unity feedback system is characterized by the open loop transfer function

$$G(s) = \frac{1}{s(0.5s+1)(0.2s+1)}$$

The steady state errors for unit-step and unit-ramp inputs are respectively

- (a) 0 and 0
- (b) 0 and 1
- (c) 1 and 0
- (d) 1 and 1

119. Ans: (b)

Sol: Unit step Input:
$$e_{ss} = \frac{A}{1 + K}$$

$$K_{p} = \underset{S \to 0}{\text{Lt}} G(s) = \underset{S \to 0}{\text{Lt}} \frac{1}{s(0.5s+1)(0.2s+1)} = \infty$$

$$e_{ss} = \frac{A}{1+\infty} = 0$$

Unit Ramp input: $e_{ss} = \frac{A}{K_s}$

$$K_{v} = \underset{s \to 0}{\text{Lt } s} G(s) = \underset{s \to 0}{\text{Lt } s} \frac{1}{s(0.5s+1)(0.2s+1)}$$
$$K_{v} = 1$$
$$e_{ss} = \frac{1}{1} = 1$$

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- 120. Which of the following statements are correct?
 - 1. A continuous time system is said to be time invariant if the parameters of the system do not change with time
 - 2. The characteristics of time-invariant system are fixed over a time
 - 3. If the input to the time invariant system is delayed by t₀ second, the characteristics of the output response is also delayed by t₀ seconds
 - (a) 1 and 2 only

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- (b) 1 and 3 only
- (c) 2 and 3 only
- (d) 1,2 and 3
- 120. Ans: (d)
- 121. A single-phase full wave rectifier uses semiconductor diodes. The transformer voltage is 35 V rms to center tap. The load consists of a 40 μ F capacitor in parallel with a 250 Ω resistor. The diode and transformer resistances and leakage reactance are neglected. If the power line frequency is 50 Hz, the dc current in the circuit will be
 - (a) 132 mA (b) 144 mA
 - (c) 156 mA

(d) 168 mA

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121. Ans: (a)

Sol: $V_{max} = V_m = 35V_2 = 49.5Volts$

We can write, $V_{dc} = I_{dc}R_L = V_m - \frac{I_{dc}}{4f_c}$

:
$$I_{dc} = \frac{V_m}{R_L + \frac{1}{4fc}} = \frac{V_m}{R_L + R_0}$$

 \therefore Here, $R_L = 250\Omega$

250 + 125

$$R_{0} = \frac{10}{4fc} = \frac{1}{4 \times 50 \times 40 \times 10^{-6}} = 125\Omega$$

: I = -\frac{49.5}{-132mA}

- 122. Silicon dioxide (SiO₂) is used in ICs, because it
 - (a) Facilitates the penetration of diffusants
 - (b) Has high heat conduction
 - (c) Prevents diffusion of impurities
 - (d) Controls the concentration of diffusants

122. Ans: (c)

Sol: SiO₂ Features

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- (i) It is easy to fabricate SiO₂ on top of silicon substrate
- (ii) It does not allow diffusion of impurities through it
- (iii) It dissolves only in Hydrofluoric Acid
- 123. Consider an n-channel MOSFET with parameters

 $K_n = 0.25 \text{ mA/V}^2$, $V_{TN} = 1 \text{ V}$, $\lambda = 0$, $C_{gd} = 0.04 \text{ pF}$ and $C_{gs} = 0.2 \text{ pF}$

If the transistor is biased at $V_{GS} = 3$ V, the unity gain bandwidth of an FET will be

- (a) 626 MHz
- (b) 646 MHz
- (c) 663 MHz
- (d) 683 MHz
- 123. Ans: (c)
- **Sol:** Unity gain bandwidth $A_i \approx \frac{g_m \sin ce}{j\omega (C_{gs} + C_{gd})} ce$ 199

The unity-gain frequency f_T is defined as the frequency at which the magnitude of the short-circuit current gain is 1.

The unity-gain frequency or bandwidth

$$f_{T} = \frac{g_{m}}{2\pi (C_{gs} + C_{gd})}$$

$$g_{m} = 2k_{n}(V_{GS} - V_{T}) = 1mA/V$$

$$f_{T} = \frac{1 \times 10^{-3}}{2\pi (0.2 + 0.04) \times 10^{-12}} \approx 663 \text{ MHz}$$

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124. The voltage gain of CE amplifier circuit can be approximated for an ideal input ac source and is given by

(a)
$$A_{V_s} = \frac{r'_e}{(R_c \times R_L)}$$

(b) $A_{V_s} = -\frac{r'_e}{(R_c \parallel R_L)}$
(c) $A_{V_s} = -\frac{(R_c \parallel R_L)}{r'_e}$
(d) $A_{V_s} = \frac{(R_c \times R_L)}{r'_e}$

Where : R_L = Load resistance

 R_C = Collector resistance

 r'_e = Effective resistance at input of transistor from emitter resistance R_E

124. Ans: (c)

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Sol: Voltage gain $A_v = -\frac{h_{fe}R_L}{h_{in}}$ (1) [:: ideal voltage source, $R_s = 0$]

Where
$$\frac{h_{fe}}{h_{ie}} = g_m \& R_L = R_C //R_L$$
 (2)
 $\Rightarrow A_V = -g_m R_C //R_L$ (3)
 $\therefore A_V = -\frac{R_C //R_L}{r_e}$ (4) $\left[\because g_m = \frac{1}{r_e}\right]$

- 125. The advantage of using a Class-B push-pull transistor amplifier over a Class-A push-pull transistor amplifier is
 - (a) A negligible power loss at no input signal
 - (b) Harmonic distortion is lower
 - (c) Self-bias can be used
 - (d) Supply voltages have good regulation
- 125. Ans: (a)
- Sol: Case (i): In class-A push-pull amplifiers, the conduction angle of transistors used in the circuit is 360°. i.e the transistors are biased in such a way that they are kept ON for ever. Therefore there will be considerable amount of power loss in the transistors in the absence of input signal.

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Case (ii): In class-B push-pull amplifiers, the conduction angle of each transistor is 180° i.e the transistors are biased in such a way that each transistor conductor for one half-cycle of input. Therefore there will negligible power loss at no input signal. [Both the transistors will be OFF at no input signal hence they will not draw any power from power supply]

- 126. The overall decibel (dB) voltage gain of a multistage amplifier is
 - (a) The dB voltage gain of the first stage
 - (b) The product of the dB voltage gains of the individual stages
 - (c) The sum of the dB voltage gains of the individual stages
 - (d) The dB voltage gain of the last stage

126. Ans: (c)

Sol: In a multistage amplifier, the overall gain is given by

$$\mathbf{A}_{\mathbf{V}_{\text{overall}}} = \mathbf{A}_{\mathbf{V}_{1}} \times \mathbf{A}_{\mathbf{V}_{2}} \times \dots \times \mathbf{A}_{\mathbf{V}_{n}}$$
(1)

- : overall decibel (dB) voltage gain, $A_{V_{overall}} dB = 20 \log [A_{V_1} \times A_{V_2} \times \times A_{V_n}]$
- = 20log A_{v_1} + 20log A_{v_2} + + 20log A_{v_n} dB
- $A_{V_{overall}} dB = A_{V_1} dB + A_{V_2} dB + \dots + A_{V_n} dB$
- 127. If an op-amp having specified signal bandwidth (BW) of 1 MHz and closed loop gain $A_{CL} = 200$ V/mV, the cutoff frequency f_c will be Since 1995
 - (a) 25 Hz (b) 15 Hz (d) 1 Hz

127. Ans: (c)

Sol: Unity gain B.W of op-Amp = 1MHz ____(1)

Method (1):

Unity gain (A=1) × 1MHz = $A_{CL} \times f_C$ (2)

:.
$$f_{\rm C} = \frac{1 \times 1 \times 10^6 \,\text{Hz}}{200 \times 10^3} = 5 \,\text{Hz}$$
 (3)

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Method (2):

The frequency of input signal at which the gain of an amplifier becomes unity is called as Unity-Gain Band width of that amplifier.

i.e

$$|A| = 1 = \frac{A_{CL}}{\sqrt{1 + \left(\frac{f}{f_{C}}\right)^{2}}}$$
 (1)

Where f is the frequency at which gain = 1

i.e.,
$$f = BW$$

$$\approx \frac{A_{CL}}{\sqrt{\left(\frac{f}{f_{C}}\right)^{2}}}$$
[:: f = BW>> f_C]
$$= \frac{f_{C}}{f} \times A_{CL}$$
(3)
$$\therefore f_{C} = \frac{f}{A_{CL}} = \frac{1MHz}{200 \times 10^{3}} = 5Hz$$
(4)

128. If the bias current in the IC-741 op-amp is $I_Q = 19 \ \mu A$ and the internal frequency compensation capacitor $C_1 = 30 \ pF$, the slew rate of the op-amp will be nearly

(a)
$$1.58 \text{ V/}\mu\text{s}$$
 (b) $1.26 \text{ V/}\mu\text{s}$ (c) $0.93 \text{ V/}\mu\text{s}$ (d) $0.63 \text{ V/}\mu\text{s}$

128. Ans: (d)

Sol: Slew rate of an op-amp =
$$\left[\frac{dV_0}{dt}\right]_{max}$$
 (1)
= $\frac{I_{Bias}}{C_{compensation}}$ (2)
= $\frac{I_0}{C_i}$ (3)
= $\frac{19\mu A}{30pF}$ (4)
= 0.633V/µsec (5)

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- 129. Which one of the following statements regarding slew rate is correct?
 - (a) It signifies how rapidly the output of an op-amp can change in response to changes in the

frequency of the input signal

- (b) It does not change with change in voltage gain
- (c) It should be smaller for high-speed op-amp applications
- (d) It is not fixed for an op-amp

129. Ans: (a)

Sol: Definition of slew Rate:

The maximum rate of change in the output of an op-Amp is considered as its slew Rate.

i.e Slew Rate = $\left[\frac{dV_0}{dt}\right]_{max}$ (1)

- 130. Which one of the following is correct for an ideal operational amplifier?
 - (a) Input resistance $R_i = \infty$, output resistance $R_o = 0$ and bandwidth = 0
 - (b) Input resistance $R_i = 0$, output resistance $R_o = \infty$ and bandwidth = 0
 - (c) Input resistance $R_i = \infty$, output resistance $R_o = 0$ and bandwidth = ∞
 - (d) Input resistance $R_i = 0$, output resistance $R_o = 0$ and bandwidth = ∞

130. Ans: (c)

- Sol: Characteristics of an ideal op-Amp:
 - $(1) A = \infty$
 - (2) $R_i = \infty$
 - (3) $R_0 = 0$
 - (4) U.G.B.W (Unity Gain Band Width) (or) Specified signal bandwidth = ∞
- 131. The advantage of ILD over LED is
 - (a) ILD emits incoherent light where as LED emits coherent light
 - (b) In ILD it is difficult to couple light whereas in LED it is easy to couple light
 - (c) In ILD coupling loss is more whereas in LED coupling loss is less
 - (d) ILD emits coherent light whereas LED emits incoherent light
- 131 Ans: (d)

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Sol: ILD emits coherent light where as LED emits incoherent light

LED – Light Emitting Diode source of incoherent light

ILD – Injection Laser Diode source of coherent light

Advantages of ILD over LED

 \rightarrow It is easier to couple light emitted by the ILD into an optical fibre cable. This reduces the coupling losses and allows smaller fibers to be used

 \rightarrow ILDs provide a higher drive power so that it operate over longer distances.

 \rightarrow ILDs can be used at higher bit rates than LEDs

 \rightarrow ILDs generate monochromatic light, which reduces chromatic (or) wavelength dispersion

132. The quantum efficiency η for the photo-detector is

(a)
$$\frac{I_{ph}}{P_o}$$

 $(b) \; \frac{I_{_{ph}}/e}{P_{_o}/(hc/\lambda)}$

(c)
$$\frac{P_o}{I_{ph}}$$

(d)
$$\frac{P_o/(hc/\lambda)}{I_{nh}/e}$$

Where $I_{ph} = Average photocurrent$

 $P_o = Average$ incident optical power

 $hc/\lambda = incident photon energy$

132 Ans: (b)

Sol: Quantum efficiency $\eta = \frac{\text{number of electron hole pairs generated}}{\text{number of photons that are incident}}$

$$=\frac{\left(I_{\rm ph}/e\right)}{\left(P_{\rm o}/h\nu\right)}=\frac{\left(I_{\rm ph}/e\right)}{\left[P_{\rm o}/(hc/\lambda)\right]}\qquad \because \nu=\frac{C}{\lambda}$$

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- 133. According to Kirchhoff's voltage law, the algebraic sum of all the voltage in any closed loop of a network is always
 - (a) Negative
 - (b) Positive
 - (c) Zero
 - (d) Determined by the battery emf

133. Ans: (c)

Sol: Definition of KVL: KVL is applicable any closed path

The algebraic sum of all current in any closed path is zero.

- 134. Ohm's law is applicable to
 - (a) DC circuit only
 - (b) AC circuit only
 - (c) DC circuit as well as AC circuit, provided account is taken of the induced emf resulting from the self-inductance of circuit and of the distribution of current in cross-section of circuit
 - (d) DC circuit as well as AC circuit, provided account is taken of the induced emf resulting from mutual-inductance of circuit and of the distribution of current in cross-section of circuit.

134. Ans: (c)

135. A car having an axle of 2 m length is travelling with 72 km/h at a vertical component of the earth's magnetic field of 40 μWb/m², the emf generated in the axle of a car will be
(a) 1.2 mV
(b) 1.6 mV

(d) 2.6 mV

- (c) 2.2 mV
- 135. Ans: (b)
- Sol: E = Blv

$$=40\times10^{-6}\times2\times\frac{72000}{3600}$$

= 1.6mV

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136.	Crest factor for an alternating current source	e is the	e ratio of
	(a) Maximum value to RMS Value		
	(b) RMS value to Maximum value		
	(c) RMS value to Average value		
	(d) Maximum value to average value		
136.	Ans: (a)		
Sol: (Crest factor is also called peak factor		
(Crest factor = $\frac{\text{Peak}(\text{or}) \text{ Maximum value}}{\text{RMS value}}$		
137.	A 200 KVA, 3300/240 V, 50 Hz single-pha	se trar	sformer has 80 turns on the secondary winding.
	Assuming an ideal transformer, the primary	curren	nt I_1 and secondary current I_2 on full load are
	nearly	А	40
	(a) 60.6 A and 833 A	(b)	72.2 A and 833 A
	(c) 60.6 A and 720 A	(d)	72.2 A and 720 A
137.	Ans: (a)		
Sol:	200KVA, 3300/240V, f = 50 Hz		
	Sec turns, $N_s = 80$, $I_1 \& I_2$ on F.L = ?		
	V ₁ I ₁ = 200KVA		
	$(3300)I_1 = 200KVA$		
	$I_1 = \frac{200 \times 10^3}{3300} = 60.6A$ Since	ce 1	995
	$V_2I_2 = 200KVA$		
	$(240)I_2 = 200KVA$		
	$I_2 = \frac{200 \times 10^3}{240} = 833.33A$		

138. Consider the following date regarding the name plate of 1-phase, 4-pole induction motor: Output = 373 W; 230 V, frequency = 50 Hz, input current = 2.9 A, power factor = 0.71, speed = 1410 rpm. The efficiency of motor will be nearly
(a) 72.8%
(b) 78.8%
(c) 84.4%
(d) 88.4%

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138. Ans: (b)

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Sol: $1 - \phi$, P = 4, output = 373 watt, V = 230V, f = 50 Hz Input current = 2.9A, p.f = 0.71, N = 1410 rpm, η = ? Input = VIcos ϕ = 230×2.9×0.71

= 473.57w $\eta = \frac{\text{output}}{\text{input}} = \frac{373w}{473.57w} \times 100 = 78.76\%$

139. Two capacitors of 80 µF and 50 µF are connected in series. When 200 V at 50 Hz are applied across the series circuit, the maximum energy stored in the circuit will be



Maximum energy stored by the capacitor combination,

$$W_{\rm C} = \frac{1}{2} C V_{\rm max}^2 = \frac{1}{2} C \left(\sqrt{2} V_{\rm rms} \right)^2$$
$$= \frac{1}{2} \times 30.77 \times 10^{-6} \times 200 \times 200 \times 2$$
$$= 1.23 J$$

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Engineering Publications	69		E & T Engineering				
40. In a 4-pole dynamo the flux/pole is 15mWb. If armature is driven at 600 rpm, the average emf							
induced in one of the armature conductors v	vill be						
(a) 0.3 V (b) 0.4 V	(c)	0.5 V	(d) 0.6 V				
140. Ans: (a)							
Sol: $P=4$, $\phi = 15 \times 10^{-3}$ Wb, N = 600 rpm,							
$E_g / \text{cond} = \frac{\phi NP}{60A} = \frac{15 \times 10^{-3} \times 600 \times 4}{60 \times 2}$							
= 0.3 V							
(assumption: wave connected)							
141. Two coils are connected in parallel and a vo	oltage	of 200 V is a	pplied to the terminals.				
The total current taken is 15 A and the pow	er diss	ipated in one	of the coils is 1500 W, the				
resistance of each coil will be nearly	A	~~~					
(a) 26.7 Ω and 23.4 Ω (b) 2	22.4 Ω	and 23.4Ω	3				
(c) 26.7 Ω and 26.7 Ω (d) 2	22.4 Ω	and 26.7 Ω					
141. Ans: (c)							
Sol: I For D.C V^+ R_1 R_2 V^+ $S.0$.C R ₂ S.C 995					
V = 200V, I = 15A							
Total power dissipated is $P = VI = (200) 15$ = 3000 Watts		; E					
Coil (1) \rightarrow P ₁ = 1500W (given)							
Coil (2) \rightarrow P ₂ = VI – P ₁ = 3000 – 1500							
= 1500 Watts							
$P_1 = P_2 \Longrightarrow R_1 = R_2 = R \Longrightarrow R_q = \frac{R}{2}$							
$\frac{\mathrm{V}^2}{\mathrm{R}_{\mathrm{eq}}} = 3000 \Longrightarrow \mathrm{R}_{\mathrm{eq}} = \frac{\mathrm{V}^2}{3000}$							
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$$R_{eq} = \frac{(200)^2}{3000} = \frac{40}{3} = 13.33$$

$$\frac{R}{2} = 13.33 \Longrightarrow R = 26.67$$

Resistors $R_1 = R_2 = 26.07\Omega$

142. The value of total potential difference created between the electrodes, when the cell is **not** connected to an external circuit is known as its

- (a) Electromotive force (b) Electrostatic force
- (c) Electromagnetic force (d) Electrochemical force
- 142. Ans: (a)
- Sol: The value of total potential difference created between the electrodes when cell is not connected is called electromotive force.
- 143. The cells are connected in two rows in parallel to pass a current of 6 A through an external resistance 0.7 Ω . If the electromotive force of each cell is 2.1 volts and internal resistance 0.5 Ω , the minimum number of cells will be

	(a) 10 cells	(b) 12 cells	(c) 14 cells	(d) 16 cells
143.	Ans: (c)			
Sol:	$0.5\Omega \overset{1}{\gtrless}$	\$ 0.5Ω	6A	
	2.1V T	$\frac{1}{T}2.1V$	0.7Ω	
	0.5Ω Š	§ 0.5Ω	Since 1995	
	$2.1V \pm$	$\frac{1}{\tau}$ 2.1V		
	0.5Ω Š	≹ 0.5		
	$2.1V \pm$	$\frac{1}{T}$ 2.1V		
	0.5Ω ≹	≹0.5Ω		
	$2.1V \pm$	$\frac{1}{T}$ 2.1V		
	0.5Ω	≹ 0.5Ω		
	$2.1V \pm$	$\frac{1}{T}$ 2.1V		
	0.5Ω ≹	≹0.5Ω		
	$2.1V \frac{1}{T}$	$\frac{1}{T}$ 2.1V		
	0.5Ω	≹0.5Ω		
	2.1V	<u> </u>	∴14 cells	

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7 cells are in row

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 \therefore 14 cells in two rows

$$\therefore (2.1) \times 7 = 14.7 \text{V}$$

r = R_T =
$$\frac{(0.5 \times 7)}{2}$$
 = 1.75,
∴ I = $\frac{V}{r + R_L}$ ⇒ 6 = $\frac{14.7}{1.75 + 0.7}$ = 6A

144. Which of the following are the active materials of a lead acid cell?

1. Lead Peroxide (PbO₂) for positive plate

2. Sponge Lead (Pb) for negative plate

3. Concentrated Sulphuric acid (H₂SO₄) as electrolyte

- 4. Dilute Sulphuric acid (H₂SO₄) as electrolyte
- (a) 1, 2 and 3 only (b) 1, 2 and 4 only
- (c) 1 and 3 only

(d) 2 and 4 only

144. Ans: (b)

- Sol: Active materials of a lead acid cell are
 - (i) Lead peroxide (PbO₂) for positive plate
 - (ii) Sponze Lead (Pb) for negative plate
 - (iv) Dilute Sulphuric acid (H₂SO₄) as electrolyte.

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- 145. Which of the following materials are used for high-technology applications?
 - 1. Semi conductors
 - 2. Bio materials
 - 3. Smart materials
 - (a) 1 and 2 only (b) 1 and 3 only (c) 2 and 3 only (d) 1, 2 and 3

145. Ans: (d)

- Sol: The materials used for high technology applications are,
 - 1. Semiconductors
 - 2. Bio materials
 - 3. Smart mahials

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146. The theoretical density ρ for the crystal structure of a metallic solid is

(a)
$$\frac{nV_{c}}{AN_{A}}$$
 (b) $\frac{nN_{A}}{AV_{c}}$ (c) $\frac{nA}{V_{c}N_{A}}$ (d) $\frac{nAN_{A}}{V_{c}}$

Where n = number of atoms associated with each unit cell

 $V_C =$ Volume of unit cell

A = Atomic weight

 $N_A = Avogadro's$ number

146. Ans: (c)

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Sol: The theoretical density = $\frac{n \times AW}{AN \times V_{uc}}$

n = effective number of atoms inside unit cell

AW = Atomic weight

- AN = Avagadro's number
- $V_{vc} = Volume of unifull$

So,
$$\rho = \frac{nA}{N_A V_C}$$

147. A circular dislocation loop has edge character all round the loop and this dislocation can glide only on a surface that contains

(d) No vector

(a) Burgers vector

(c) t vector

(b) Both burgers vector and t vector

147. Ans: (b)

Sol: In edge dislocation burger's vector and t vector are perpendicular to each other.

148. The critical stress σ_c for crack propagation in a brittle material, using the principles of fracture mechanics is

(a)
$$\left(\frac{2E\gamma_s}{3\pi a}\right)^{\frac{1}{2}}$$
 (b) $\left(\frac{3E\gamma_s}{2\pi a}\right)^{\frac{1}{2}}$ (c) $\left(\frac{2E\gamma_s}{\pi a}\right)^{\frac{1}{2}}$ (d) $\left(\frac{3E\gamma_s}{\pi a}\right)^{\frac{1}{2}}$

Where: E = Modulus of elasticity

 $\gamma_s =$ Specific surface energy

a = One half the length of an internal crack

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148. Ans: (c)

Sol: Fracture strength from Griffith's formula

$$\sigma_{\rm fra} = \left(\frac{2 {\rm E} \gamma_{\rm S}}{\pi {\rm a}}\right)^{\frac{1}{2}}$$

E = Modulus of elasticity

 γ_s = Specific surface energy

- a = one half the length of an internal crack
- 149. Ceramic materials are
 - (a) Organic and metallic
 - (c) inorganic and non metallic
- (b) Inorganic and metallic
- (d) Organic and non metallic

149. Ans: (c)

Sol: Ceramics are compounds of both metal & non metal and inorganic materials Ex: Nacl

- 150. Which of the following points are important on the viscosity scale in the fabrication and processing of glasses?
 - 1. Softening point
 - 2. Working point
 - 3. Melting point
 - (a) 1 and 2 only
 - (c) 2 and 3 only

150. Ans: (d)

Sol: The important points on the viscosity scale in the fabrication and processing of glasses are

Since 1995

- 1. Softening point
- 2. Working point
- 3. Melting point

(b) 1 and 3 only (d) 1, 2 and 3

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